SG2M040120JJ

SG2M [illegible] 120

1200V Si [illegible] r MOS

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Features 1

Benefits .....

1 Maximum ratings

Table 2 Maximum rating

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3.3 Switching characteristics

Table 6 Dynamic characteristics

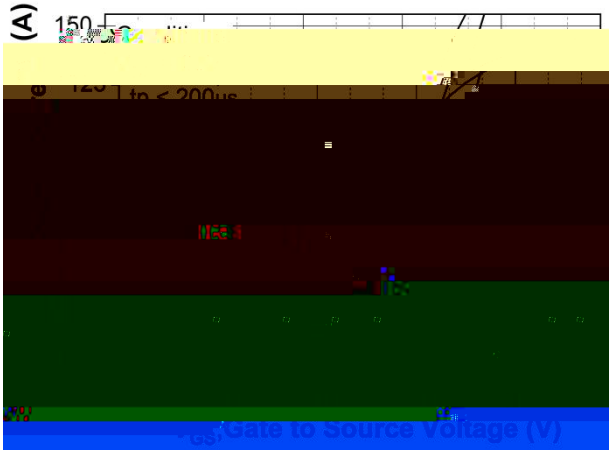
Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions	Note

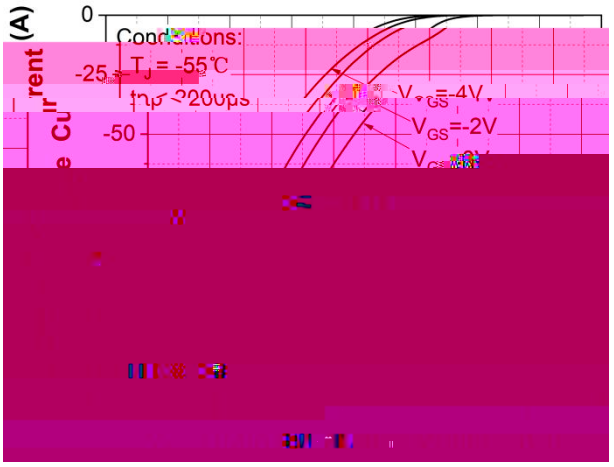
Table 7 Body diode characteristics

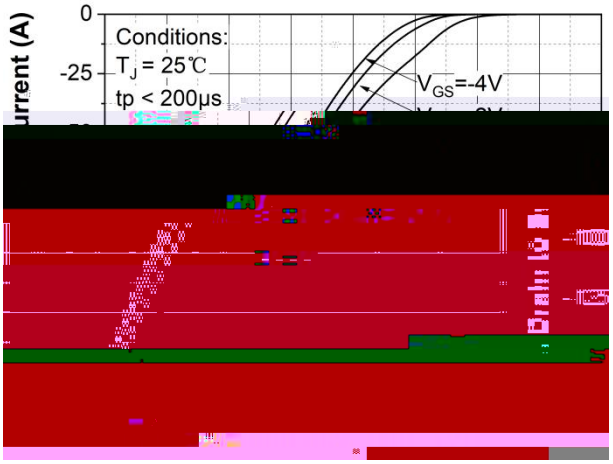
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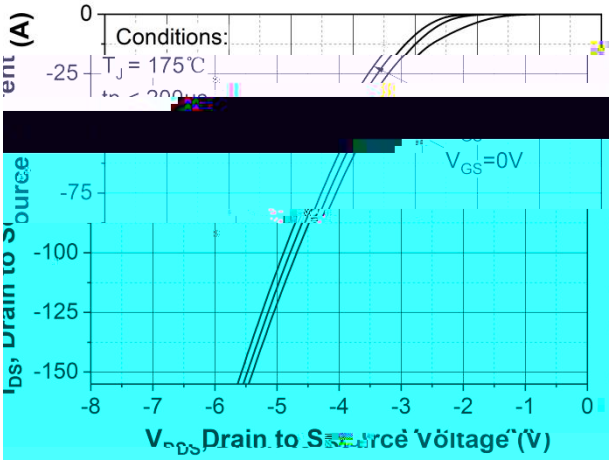
4 Electrical characteristic diagrams

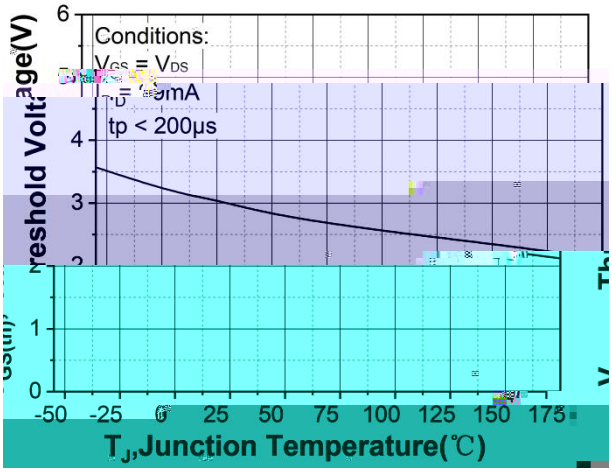
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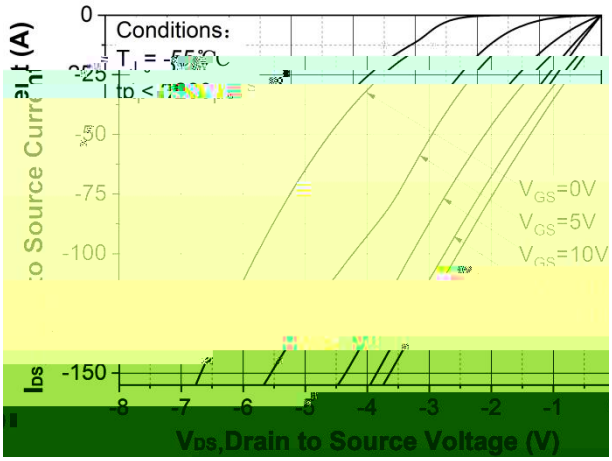


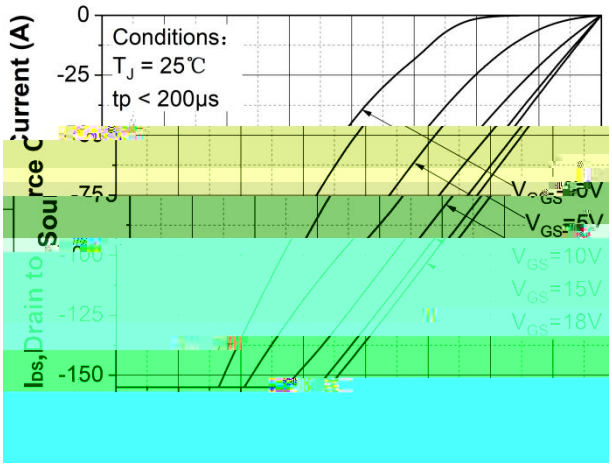


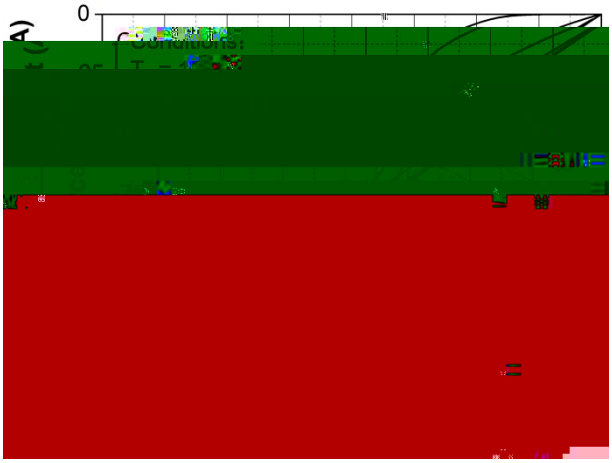


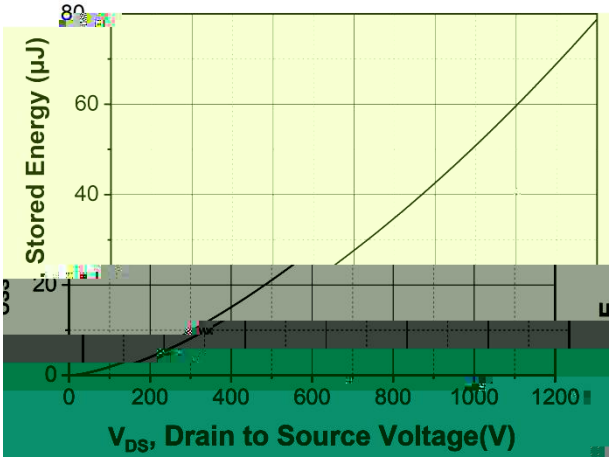


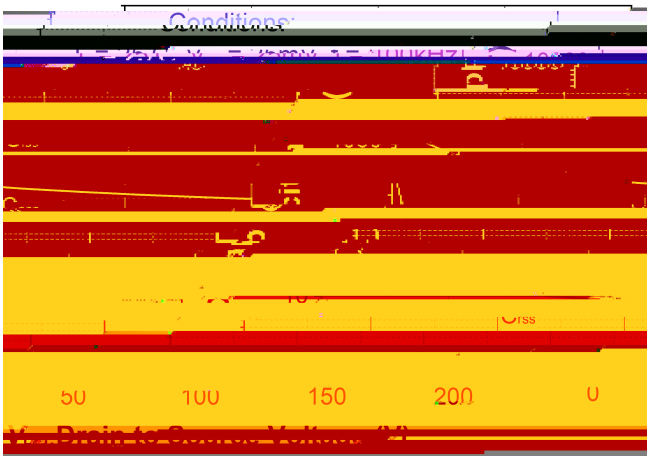
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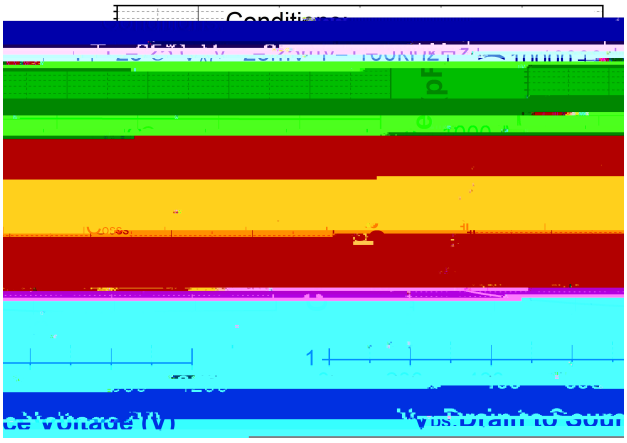






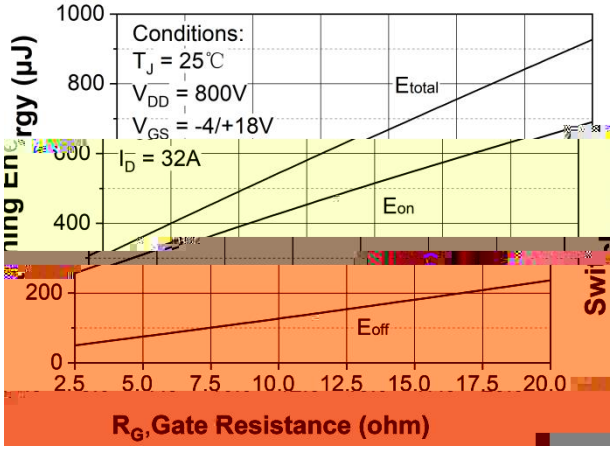


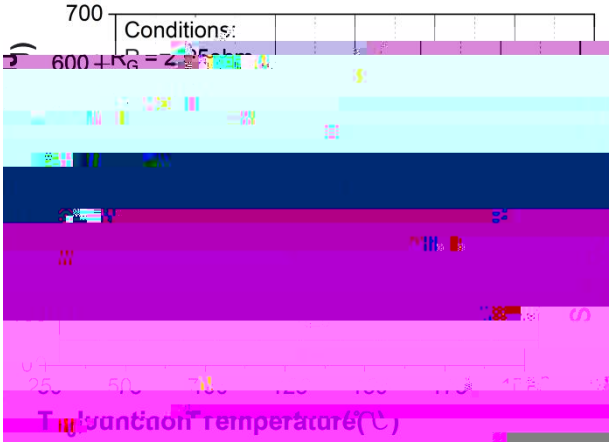


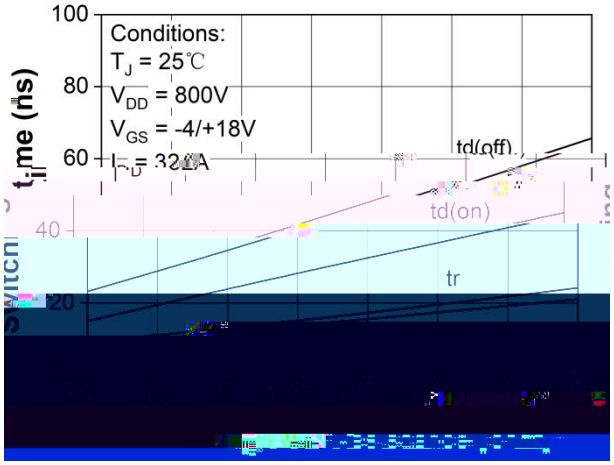


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1200V SiC Power MOSFET

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